

BSC160N10NS3GATMA1

Data Sheet

N-Channel 100 V 16 mOhm OptiMOS? Power-Transistor - PG-TDSON-8

Manufacturers	Infineon Technologies Corporation	
Package/Case	PG-TDSON-8	1 TIT
Product Type	Transistors	
RoHS	Green	
Lifecycle		Images are for reference only
Please submit RFO	for BSC160N10NS3GATMA1 or Email to us: sales@ovaga.c	com We will contact you in 12 hours. RFO

General Description

Infineon's 100V OptiMOSTM power MOSFETs offer superior solutions for high efficiency, high power-density SMPS. Compared to the next best technology this family achieves a reduction of 30% in both R DS(on) and FOM (figure of merit).

Features

Application

Class D audio amplifiers

Uninterruptable power supplies (UPS)

Synchronous rectification for AC-DC SMPS

Isolated DC-DC converters (telecom and datacom systems

Or-ing switches and circuit breakers in 48V systems

Motor control for 48V-80V systems (i.e. domestic vehicles, power-tools, trucks)

Excellent switching performance

Very low Q g and Q gd

World's lowest R DS(on)

Excellent gate charge x R DS(on) product (FOM)

RoHS compliant-halogen free

MSL1 rated 2

- Environmentally friendly
- Increased efficiency

Highest power density

- Less paralleling required
- Smallest board-space consumption
- Easy-to-design products

Related Products



BSP613P

Infineon Technologies Corporation SOT-223



BSB013NE2LXI

Infineon Technologies Corporation WDSON-2



BSC030N08NS5ATMA1 Infineon Technologies Corporation TDSON-8



BSC016N06NSATMA1 Infineon Technologies Corporation DSON-8









BSC011N03LS

Infineon Technologies Corporation PG-TDSON-8

BSC014N04LSATMA1

Infineon Technologies Corporation tdson-8

BSC026N08NS5ATMA1

Infineon Technologies Corporation TDSON-8

BSC066N06NSATMA1

Infineon Technologies Corporation TDSON-8